








	<h2 style="color: red;">FQP15P12</h2>
	<p>Hersteller-Teilenummer: FQP15P12</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET P-CH 120V 15A TO-220</p> <p>Datenblätter: 1.FQP15P12.pdf 2.FQP15P12.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 51787 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP15P12
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET P-CH 120V 15A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	51787 pcs Stock
detaillierte Beschreibung	P-Channel 120V 15A (Tc) 100W (Tc) Through Hole
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	100W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	120V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	15A (Tc)
Rds On (Max) @ Id, Vgs	200 mOhm @ 7.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	38nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1100pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

FQP15P12 ist neu im Original, Suche FQP15P12 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP15P12 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQP15P12: Info@Y-IC.com

Sie können auch interessiert sein:

 FQP15P12 Fairchild/ON Semiconductor MOSFET P-CH 120V 15A TO-220	 FQP15N65 Fairchild/ON Semiconductor FQP15N65 FAIRCHILD	 FQP15N80 Fairchild/ON Semiconductor FQP15N80 FAIRCHILD	 FQP15N60 Fairchild/ON Semiconductor FQP15N60 FAIRCHILD
 FQP16N25 Fairchild/ON Semiconductor MOSFET N-CH 250V 16A TO-220	 FQP16N15 AMI Semiconductor / ON Semiconductor MOSFET N-CH 150V 16.4A TO-220	 FQP15N60C Original TO-220	 FQP16N25 AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 16A TO-220

heiße Teile

Mehr

⊕ FQP13N06L	↔ FQP13N06L	⇒ FQP13N10	D FQP13N10	↗ FQP13N10L
⊕ FQP13N10L	⊕ FQP13N50	D FQP13N50	⇒ FQP13N50C	↗ FQP13N50C
⊕ FQP13N60C	⊕ FQP140N03	⊕ FQP140N03L	↔ FQP14N15	↗ FQP14N15
D FQP14N30	⊕ FQP14N30	⊕ FQP14N80	⊕ FQP14N80C	↗ FQP15N16
⇒ FQP15N30	↔ FQP15N50	⊕ FQP15N60	⊕ FQP15N65	↗ FQP15N80
↔ FQP15P12	⇒ FQP16N15	D FQP16N15	⊕ FQP16N25	⊕ FQP16N25
⊕ FQP16N25C	D FQP16N25C	⇒ FQP17N08	↔ FQP17N08	↗ FQP17N08L
⊕ FQP17N08L	⊕ FQP17N40	↔ FQP17N40	⇒ FQP17P06	↗ FQP17P06
⊕ FQP17P10	⊕ FQP17P10	⊕ FQP18N20V2	D FQP18N20V2	↗ FQP18N50V2
↔ FQP18N50V2	⊕ FQP19N10	⊕ FQP19N10	⊕ FQP19N10L	↗ FQP19N10L

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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